

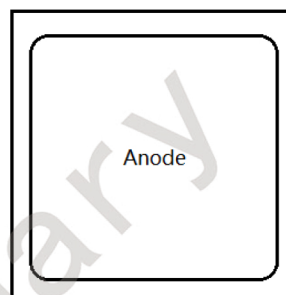
GSD06120

1200V Silicon Carbide Schottky Diode



Features

- Negligible reverse recovery
- High surge current
- Positive temperature coefficient
- Higher frequency
- Halogen-free / RoHS compliant



Applications

- SMPS
- Solar inverter
- Data Center
- UPS

Benefits

- High-speed switching
- Low heat dissipation requirements
- Reduce size and cost of the system
- High-reliability

Die Information

Wafer Size	150 mm
Die Size	1880 × 1880 μm^2 (exclude SL)
Scribe Line Size	60 μm
Die Thickness	175 μm
Anode Pad Opening Size;	1553 × 1553 μm^2
Gross Die	4196 ea
Top Metallization	Al, 4 μm
Back Metallization	Ti/Ni/Ag, 2.5 μm
Frontside Passivation	Polyimide
Wire Bond	Al, 10mil×1 (recommend)

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Electrical Characteristics (Wafer Type)

Maximum Ratings^{*2} (Tc=25°C unless otherwise noted)

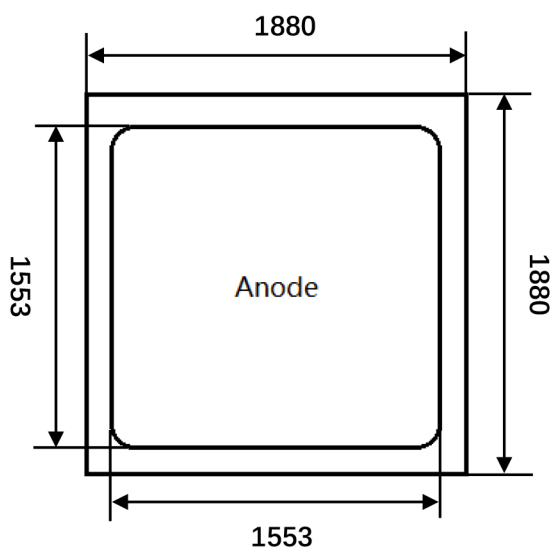
Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		1200	V
I_F	Continuous forward current	Tc=161°C	6	A
I_{FSM}	Non-repetitive forward surge current	$t_p=10ms$, Half sine pulse	48	A
I_{FRM}	Repetitive Peak Forward Surge Current	$t_p=10ms$, Half sine pulse	40	A

*2. Based on TO-220-2 package

Static Electrical Characteristics (Tc=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
V_R	Reverse blocking voltage	$I_R=60\mu A$	1200	-	-	V
I_R	Reverse current	$V_R=1200V$	-	2.0	60	μA
V_F	Forward voltage	$I_F=6A$	-	1.45	1.70	V

Die Layout (Unit : μm)



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Announcement

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